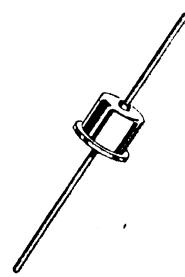


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**1N5823, 1N5824
1N5825
MBR5825H, H1**



SCHOTTKY BARRIER RECTIFIERS

5 AMPERE
20, 30, 40 VOLTS

*MAXIMUM RATINGS

Rating	Symbol	1N5823	1N5824	1N5825 MBR5825H, H1	Unit
Peak Repetitive Reverse Voltage	V _{RRM}				
Working Peak Reverse Voltage	V _{RWM}	20	30	40	Volts
DC Blocking Voltage	V _R				
Non-Repetitive Peak Reverse Voltage	V _{RSM}	24	36	48	Volts
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	Volts
Average Rectified Forward Current V _R (equiv) ≤ 0.2 V _R (dc); T _C = 75°C V _R (equiv) ≤ 0.2 V _R (dc); T _C = 80°C R _{θJA} = 25°C/W, P.C. Board Mounting. See Note 3)	I _O				Amp
Ambient Temperature Rated V _R (dc); P _{F(AV)} = 0 R _{θJA} = 25°C/W	T _A	65	60	55	°C
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase 60 Hz)	I _{FSM}		500 (for 1 cycle)		Amp
Operating and Storage Junction Temperature Range (Reverse Voltage applied)	T _J , T _{Stg}		-65 to +125		°C
Peak Operating Junction Temperature (Forward Current Applied)	T _{J(pk)}		150		°C

*THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{θJC}	3.0	°C/W

*ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	1N5823	1N5824	1N5825 MBR5825H, H1	Unit
Maximum Instantaneous Forward Voltage (1) (I _F = 3.0 Amp) (I _F = 5.0 Amp) (I _F = 15.7 Amp)	V _F	0.330 0.360 0.470	0.340 0.370 0.490	0.350 0.380 0.520	Volts
Maximum Instantaneous Reverse Current @ rated dc Voltage T _C = 25°C T _C = 100°C	I _R	10 75	10 75	10 75	mA

(1) Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2.0% *Indicates JEDEC Registered Data for 1N5823-1N5825



Quality Semi-Conductors